MJE13005D-K

**Preliminary** 

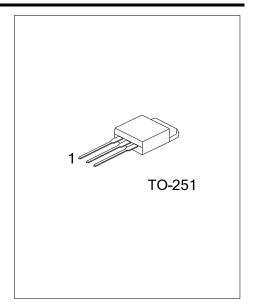
NPN SILICON TRANSISTOR

# HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

## **■** DESCRIPTION

The UTC **MJE13005D-K** is a high voltage fast-switching NPN power transistor. It is characterized by high breakdown voltage, high current capability, high switching speed and high reliability.

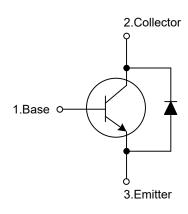
The UTC **MJE13005D-K** is intended to be used in energy-saving light, electronic ballast, high frequency switching power supply, high frequency power transform or common power amplifier, etc.



## **■ FEATURES**

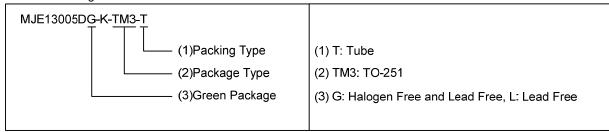
- \* High Breakdown Voltage
- \* High Current Capability
- \* High Switching Speed
- \* High Reliability
- \* RoHS-Compliant Product

#### **■ INTERNAL SCHEMATIC DIAGRAM**

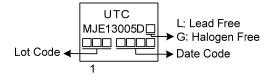


## **■ ORDERING INFORMATION**

Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MJE13005DL-K-TM3-T	MJE13005DG-K-TM3-T	TO-251	В	С	Е	Tube	



## **■ MARKING**



## ■ **ABSOLUTE MAXIMUM RATING** (T<sub>C</sub>=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATING	UNIT	
Collector- Emitter Voltage (V <sub>BE</sub> =0)		V <sub>CES</sub>	700	V	
Collector-Emitter Voltage (I <sub>B</sub> =0)		$V_{CEO}$	400	V	
Emitter-Base Voltage		$V_{EBO}$	9	V	
0-11	DC	Ic	4	Α	
Collector Current	Pulse	I <sub>CP</sub>	8	Α	
5 0 1	DC	Ι <sub>Β</sub>	2	Α	
Base Current	Pulse	I <sub>BP</sub>	4	Α	
Power Dissipation		P <sub>D</sub>	44	W	
Storage Temperature		T <sub>STG</sub>	-55 ~ <b>+</b> 150	°C	

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Pulse Test: Pulse Width = 5.0 ms, Duty Cycle < 10%.

## **■ THERMAL DATA**

PARAMETER	SYMBOL	RATING	UNIT
Junction to Ambient	$\theta_{JA}$	100	°C/W
Junction to Case	θις	2.87	°C/W

## **■ ELECTRICAL CHARACTERISTICS**

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Collector-Emitter Breakdown Voltage		BV <sub>CEO</sub>	I <sub>C</sub> =10mA, I <sub>B</sub> =0	400			V	
Collector -Base Breakdown Voltage		BV <sub>CBO</sub>	I <sub>C</sub> =1mA, I <sub>B</sub> =0	700			V	
Emitter-Base Breakdown Voltage		BV <sub>EBO</sub>	I <sub>E</sub> =1mA, I <sub>C</sub> =0	9			V	
Collect Cut-off Current		Ісво	V <sub>CB</sub> =700V, I <sub>E</sub> =0			100	μΑ	
Collect Cut-off Current		I <sub>CEO</sub>	V <sub>CE</sub> =400V,I <sub>B</sub> =0			50	μΑ	
Emitter Cut-off Current		I <sub>EBO</sub>	V <sub>EB</sub> =9V, I <sub>C</sub> =0			10	μΑ	
DC Current Gain		h <sub>FE1</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =500mA	15		50		
		h <sub>FE2</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =2A	5				
Collector-Emitter Saturation Voltage		VCE(SAT)	I <sub>C</sub> =1A, I <sub>B</sub> =0.2A			0.5		
			I <sub>C</sub> =2A, I <sub>B</sub> =0.5A			0.6	V	
			I <sub>C</sub> =4A, I <sub>B</sub> =1A			1		
			I <sub>C</sub> =2A, I <sub>B</sub> =0.5A, T <sub>C</sub> =100°C			1		
Base-Emitter Saturation Voltage		$V_{BE(SAT)}$	I <sub>C</sub> =2A, I <sub>B</sub> =0.5A			1.6	V	
Resistive Load	Fall Time	t <sub>F</sub>	V -24V   -24   -   -0.44			0.7	μs	
	Storage Time	ts	Vcc=24V, Ic=2A, I <sub>B1</sub> =-I <sub>B2</sub> =0.4A			4	μs	
Current Gain Bandwidth Product		f⊤	V <sub>CE</sub> =10V, I <sub>C</sub> =0.5A	4			MHz	
Diode Forward Voltage		VF	I <sub>F</sub> =1A			1.5	V	

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